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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	DMA, I ² S, POR, PWM, WDT
Number of I/O	52
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 1x12b, 3x16b; D/A 3x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-LQFP
Supplier Device Package	64-LQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f373r8t6

6.3.7	External clock source characteristics	72
6.3.8	Internal clock source characteristics	77
6.3.9	PLL characteristics	78
6.3.10	Memory characteristics	79
6.3.11	EMC characteristics	80
6.3.12	Electrical sensitivity characteristics	81
6.3.13	I/O current injection characteristics	82
6.3.14	I/O port characteristics	84
6.3.15	NRST characteristics	89
6.3.16	Communications interfaces	91
6.3.17	12-bit ADC characteristics	98
6.3.18	DAC electrical specifications	101
6.3.19	Comparator characteristics	103
6.3.20	Temperature sensor characteristics	105
6.3.21	V _{BAT} monitoring characteristics	105
6.3.22	Timer characteristics	105
6.3.23	USB characteristics	107
6.3.24	CAN (controller area network) interface	108
6.3.25	SDADC characteristics	108
7	Package information	115
7.1	UFBGA100 package information	115
7.2	LQFP100 package information	118
7.3	LQFP64 package information	121
7.4	LQFP48 package information	124
7.5	Thermal characteristics	127
7.5.1	Reference document	127
7.5.2	Selecting the product temperature range	128
8	Part numbering	130
9	Revision history	131

Table 49.	ESD absolute maximum ratings	81
Table 50.	Electrical sensitivities	82
Table 51.	I/O current injection susceptibility	83
Table 52.	I/O static characteristics	84
Table 53.	Output voltage characteristics	87
Table 54.	I/O AC characteristics	88
Table 55.	NRST pin characteristics	89
Table 56.	I2C characteristics	91
Table 57.	I ² C analog filter characteristics	92
Table 58.	SPI characteristics	93
Table 59.	I ² S characteristics	96
Table 60.	ADC characteristics	98
Table 61.	R _{SRC} max for f _{ADC} = 14 MHz	99
Table 62.	ADC accuracy	99
Table 63.	DAC characteristics	101
Table 64.	Comparator characteristics	103
Table 65.	Temperature sensor calibration values	105
Table 66.	TS characteristics	105
Table 67.	V _{BAT} monitoring characteristics	105
Table 68.	TIMx characteristics	106
Table 69.	IWDG min/max timeout period at 40 kHz (LSI)	106
Table 70.	WWDG min-max timeout value @72 MHz (PCLK)	106
Table 71.	USB startup time	107
Table 72.	USB DC electrical characteristics	107
Table 73.	USB: Full-speed electrical characteristics	108
Table 74.	SDADC characteristics	108
Table 75.	VREFSD+ pin characteristics	114
Table 76.	UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data	115
Table 77.	UFBGA100 recommended PCB design rules (0.5 mm pitch BGA)	116
Table 78.	LQPF100 - 100-pin, 14 x 14 mm low-profile quad flat package mechanical data	119
Table 79.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package mechanical data	122
Table 80.	LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat package mechanical data	125
Table 81.	Package thermal characteristics	127
Table 82.	Ordering information scheme	130
Table 83.	Document revision history	131

List of figures

Figure 1.	Block diagram	12
Figure 2.	STM32F373xx LQFP48 pinout	29
Figure 3.	STM32F373xx LQFP64 pinout	30
Figure 4.	STM32F373xx LQFP100 pinout	31
Figure 5.	STM32F373xx UFBGA100 ballout	32
Figure 6.	STM32F373xx memory map	48
Figure 7.	Pin loading conditions	52
Figure 8.	Pin input voltage	52
Figure 9.	Power supply scheme	53
Figure 10.	Current consumption measurement scheme	54
Figure 11.	Typical V_{BAT} current consumption (LSE and RTC ON/LSEDRV[1:0]='00')	65
Figure 12.	High-speed external clock source AC timing diagram	73
Figure 13.	Low-speed external clock source AC timing diagram	74
Figure 14.	Typical application with an 8 MHz crystal	75
Figure 15.	Typical application with a 32.768 kHz crystal	77
Figure 16.	HSI oscillator accuracy characterization results	78
Figure 17.	TC and TTA I/O input characteristics - CMOS port	85
Figure 18.	Five volt tolerant (FT and FTf) I/O input characteristics - CMOS port	86
Figure 19.	I/O AC characteristics definition	89
Figure 20.	Recommended NRST pin protection	90
Figure 21.	I ² C bus AC waveforms and measurement circuit	92
Figure 22.	SPI timing diagram - slave mode and CPHA = 0	94
Figure 23.	SPI timing diagram - slave mode and CPHA = 1 ⁽¹⁾	94
Figure 24.	SPI timing diagram - master mode ⁽¹⁾	95
Figure 25.	I ² S slave timing diagram (Philips protocol) ⁽¹⁾	97
Figure 26.	I ² S master timing diagram (Philips protocol) ⁽¹⁾	97
Figure 27.	ADC accuracy characteristics	100
Figure 28.	Typical connection diagram using the ADC	100
Figure 29.	12-bit buffered /non-buffered DAC	102
Figure 30.	Maximum V_{REFINT} scaler startup time from power down	104
Figure 31.	USB timings: definition of data signal rise and fall time	108
Figure 32.	UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package outline	115
Figure 33.	UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package recommended footprint	116
Figure 34.	UFBGA100 marking example (package top view)	117
Figure 35.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package outline	118
Figure 36.	LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint	120
Figure 37.	LQFP100 marking example (package top view)	120
Figure 38.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline	121
Figure 39.	LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package recommended footprint	123
Figure 40.	LQFP64 marking example (package top view)	123
Figure 41.	LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat package outline	124
Figure 42.	LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat package recommended footprint	126
Figure 43.	LQFP48 marking example (package top view)	126

2 Description

The STM32F373xx family is based on the high-performance ARM® Cortex®-M4 32-bit RISC core operating at a frequency of up to 72 MHz, and embedding a floating point unit (FPU), a memory protection unit (MPU) and an Embedded Trace Macrocell™ (ETM). The family incorporates high-speed embedded memories (up to 256 Kbyte of Flash memory, up to 32 Kbytes of SRAM), and an extensive range of enhanced I/Os and peripherals connected to two APB buses.

The STM32F373xx devices offer one fast 12-bit ADC (1 Msps), three 16-bit Sigma delta ADCs, two comparators, two DACs (DAC1 with 2 channels and DAC2 with 1 channel), a low-power RTC, 9 general-purpose 16-bit timers, two general-purpose 32-bit timers, three basic timers.

They also feature standard and advanced communication interfaces: two I2Cs, three SPIs, all with muxed I2Ss, three USARTs, CAN and USB.

The STM32F373xx family operates in the -40 to +85 °C and -40 to +105 °C temperature ranges from a 2.0 to 3.6 V power supply. A comprehensive set of power-saving mode allows the design of low-power applications.

The STM32F373xx family offers devices in five packages ranging from 48 pins to 100 pins. The set of included peripherals changes with the device chosen.

3.17 Timers and watchdogs

The STM32F373xx includes two 32-bit and nine 16-bit general-purpose timers, three basic timers, two watchdog timers and a SysTick timer. The table below compares the features of the advanced control, general purpose and basic timers.

Table 5. Timer feature comparison

Timer type	Timer	Counter resolution	Counter type	Prescaler factor	DMA request generation	Capture/compare channels	Complementary outputs
General-purpose	TIM2 TIM5	32-bit	Up, Down, Up/Down	Any integer between 1 and 65536	Yes	4	0
General-purpose	TIM3, TIM4, TIM19	16-bit	Up, Down, Up/Down	Any integer between 1 and 65536	Yes	4	0
General-purpose	TIM12	16-bit	Up	Any integer between 1 and 65536	No	2	0
General-purpose	TIM15	16-bit	Up	Any integer between 1 and 65536	Yes	2	1
General-purpose	TIM13, TIM14	16-bit	Up	Any integer between 1 and 65536	No	1	0
General-purpose	TIM16, TIM17	16-bit	Up	Any integer between 1 and 65536	Yes	1	1
Basic	TIM6, TIM7, TIM18	16-bit	Up	Any integer between 1 and 65536	Yes	0	0

Table 11. STM32F373xx pin definitions (continued)

Pin numbers				Pin name (function after reset)	Pin type	I/O structure	Notes	Pin functions	
LQFP100	UFPGA100	LQFP64	LQFP48					Alternate function	Additional functions
91	C5	57	41	PB5	I/O	FT	-	SPI1_MOSI/I2S1_SD, SPI3_MOSI/I2S3_SD, I2C1_SMBAL, USART2_CK, TIM16_BKIN, TIM3_CH2, TIM17_CH1, TIM19_ETR	-
92	B5	58	42	PB6	I/O	FTf	-	I2C1_SCL, USART1_TX, TIM16_CH1N, TIM3_CH3, TIM4_CH1, TIM19_CH1, TIM15_CH1, TSC_G5_IO3	-
93	B4	59	43	PB7	I/O	FTf	-	I2C1_SDA, USART1_RX, TIM17_CH1N, TIM3_CH4, TIM4_CH2, TIM19_CH2, TIM15_CH2, TSC_G5_IO4	-
94	A4	60	44	BOOT0	I	B	-	Boot memory selection	
95	A3	61	45	PB8	I/O	FTf	-	SPI2_SCK/I2S2_CK, I2C1_SCL, USART3_TX, CAN_RX, CEC, TIM16_CH1, TIM4_CH3, TIM19_CH3, COMP1_OUT, TSC_SYNC	-
96	B3	62	46	PB9	I/O	FTf	-	SPI2_NSS/I2S2_WS, I2C1_SDA, USART3_RX, CAN_TX, IR_OUT, TIM17_CH1, TIM4_CH4, TIM19_CH4, COMP2_OUT	-
97	C3	-	-	PE0	I/O	FT	(2)	USART1_TX, TIM4_ETR	-
98	A2	-	-	PE1	I/O	FT	(2)	USART1_RX	-
99	D3	63	47	VSS_1	S	-	-	Ground	
100	C4	64	48	VDD_1	S	-	-	Digital power supply	

- PC13, PC14 and PC15 are supplied through the power switch. Since the switch sinks only a limited amount of current (3 mA), the use of GPIO PC13 to PC15 in output mode is limited:
 - The speed should not exceed 2 MHz with a maximum load of 30 pF
 - These GPIOs must not be used as current sources (e.g. to drive an LED)
 After the first backup domain power-up, PC13, PC14 and PC15 operate as GPIOs. Their function then depends on the content of the Backup registers which is not reset by the main reset. For details on how to manage these GPIOs, refer to the Battery backup domain and BKP register description sections in the RM0313 reference manual.
- When using the small packages (48 and 64 pin packages), the GPIO pins which are not present on these packages, must not be configured in analog mode.
- these pins are powered by VDDSD12.
- these pins are powered by VDDSD3.

Table 18. STM32F373xx peripheral register boundary addresses⁽¹⁾ (continued)

Bus	Boundary address	Size	Peripheral
APB2	0x4001 6800 - 0x4001 6BFF	1 KB	SDADC3
	0x4001 6400 - 0x4001 67FF	1 KB	SDADC2
	0x4001 6000 - 0x4001 63FF	1 KB	SDADC1
	0x4001 5C00 - 0x4001 5FFF	1 KB	TIM19
	0x4001 4C00 - 0x4001 5BFF	4 KB	Reserved
	0x4001 4800 - 0x4001 4BFF	1 KB	TIM17
	0x4001 4400 - 0x4001 47FF	1 KB	TIM16
	0x4001 4000 - 0x4001 43FF	1 KB	TIM15
	0x4001 3C00 - 0x4001 3FFF	1 KB	Reserved
	0x4001 3800 - 0x4001 3BFF	1 KB	USART1
	0x4001 3400 - 0x4001 37FF	1 KB	Reserved
	0x4001 3000 - 0x4001 33FF	1 KB	SPI1/I2S1
	0x4001 2800 - 0x4001 2FFF	1 KB	Reserved
	0x4001 2400 - 0x4001 27FF	1 KB	ADC
	0x4001 0800 - 0x4001 23FF	7 KB	Reserved
	0x4001 0400 - 0x4001 07FF	1 KB	EXTI
	0x4001 0000 - 0x4001 03FF	1 KB	SYSCFG + COMP
-	0x4000 4000 - 0x4000 FFFF	24 KB	Reserved
APB1	0x4000 9C00 - 0x4000 9FFF	1 KB	TIM18
	0x4000 9800 - 0x4000 9BFF	1 KB	DAC2
	0x4000 7C00 - 0x4000 97FF	8 KB	Reserved
	0x4000 7800 - 0x4000 7BFF	1 KB	CEC
	0x4000 7400 - 0x4000 77FF	1 KB	DAC1
	0x4000 7000 - 0x4000 73FF	1 KB	PWR
	0x4000 6800 - 0x4000 6FFF	2 KB	Reserved
	0x4000 6400 - 0x4000 67FF	1 KB	CAN
	0x4000 6000 - 0x4000 63FF	1 KB	USB packet SRAM
	0x4000 5C00 - 0x4000 5FFF	1 KB	USB FS

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

Electromagnetic Interference (EMI)

The electromagnetic field emitted by the device are monitored while a simple application is executed (toggling 2 LEDs through the I/O ports). This emission test is compliant with IEC 61967-2 standard which specifies the test board and the pin loading.

Table 48. EMI characteristics

Symbol	Parameter	Conditions	Monitored frequency band	Max vs. [f _{HSE} /f _{HCLK}]	Unit
				8/72 MHz	
S _{EMI}	Peak level	V _{DD} - 3.3 V, T _A - 25 °C, LQFP100 package compliant with IEC 61967-2	0.1 to 30 MHz	9	dBμV
			30 to 130 MHz	26	
			130 MHz to 1 GHz	30	
			SAE EMI Level	4	-

6.3.12 Electrical sensitivity characteristics

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n+1) supply pins). This test conforms to the JESD22-A114/C101 standard.

Table 49. ESD absolute maximum ratings

Symbol	Ratings	Conditions	Class	Maximum value ⁽¹⁾	Unit
V _{ESD(HBM)}	Electrostatic discharge voltage (human body model)	T _A = +25 °C, conforming to JESD22-A114	2	2000	V
V _{ESD(CDM)}	Electrostatic discharge voltage (charge device model)	T _A = +25 °C, conforming to ANSI/ESD STM5.3.1, LQFP100, LQFP64, LQFP48 and UFBGA100 packages	II	500	

1. Guaranteed by characterization results.

Table 51. I/O current injection susceptibility

Symbol	Description	Functional susceptibility		Unit
		Negative injection	Positive injection	
I _{INJ}	Injected current on BOOT0 pin	-0	NA	mA
	Injected current on PC0 pin	-0	+5	
	Injected current on TC type I/O pins on VDDSD12 power domain: PB2, PE7, PE8, PE9, PE10, PE11, PE12, PE13, PE14, PE15, PB10 with induced leakage current on other pins from this group less than -50 µA	-5	+5	
	Injected current on TC type I/O pins on VDDSD3 power domain: PB14, PB15, PD8, PD9, PD10, PD12, PD13, PD14, PD15 with induced leakage current on other pins from this group less than -50 µA	-5	+5	
	Injected current on TTa type pins: PA4, PA5, PA6 with induced leakage current on adjacent pins less than -10 µA	-5	+5	
	Injected current on any other FT and FTf pins	-5	NA	
	Injected current on any other pins	-5	+5	

Note: *It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.*

Note: I/O pins are powered from V_{DD} voltage except pins which can be used as SDADC inputs:

- The PB2, PB10 and PE7 to PE15 I/O pins are powered from V_{DDSD12} .
- PB14 to PB15 and PD8 to PD15 I/O pins are powered from V_{DDSD3} . All I/O pin ground is internally connected to V_{SS} .

V_{DD} mentioned in the Table 52 represents power voltage for a given I/O pin (V_{DD} or V_{DDSD12} or V_{DDSD3}).

All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements is shown in Figure 17 for standard I/Os, and in Figure 18 for 5 V tolerant I/Os. The following curves are design simulation results, not tested in production.

Figure 17. TC and TTa I/O input characteristics - CMOS port

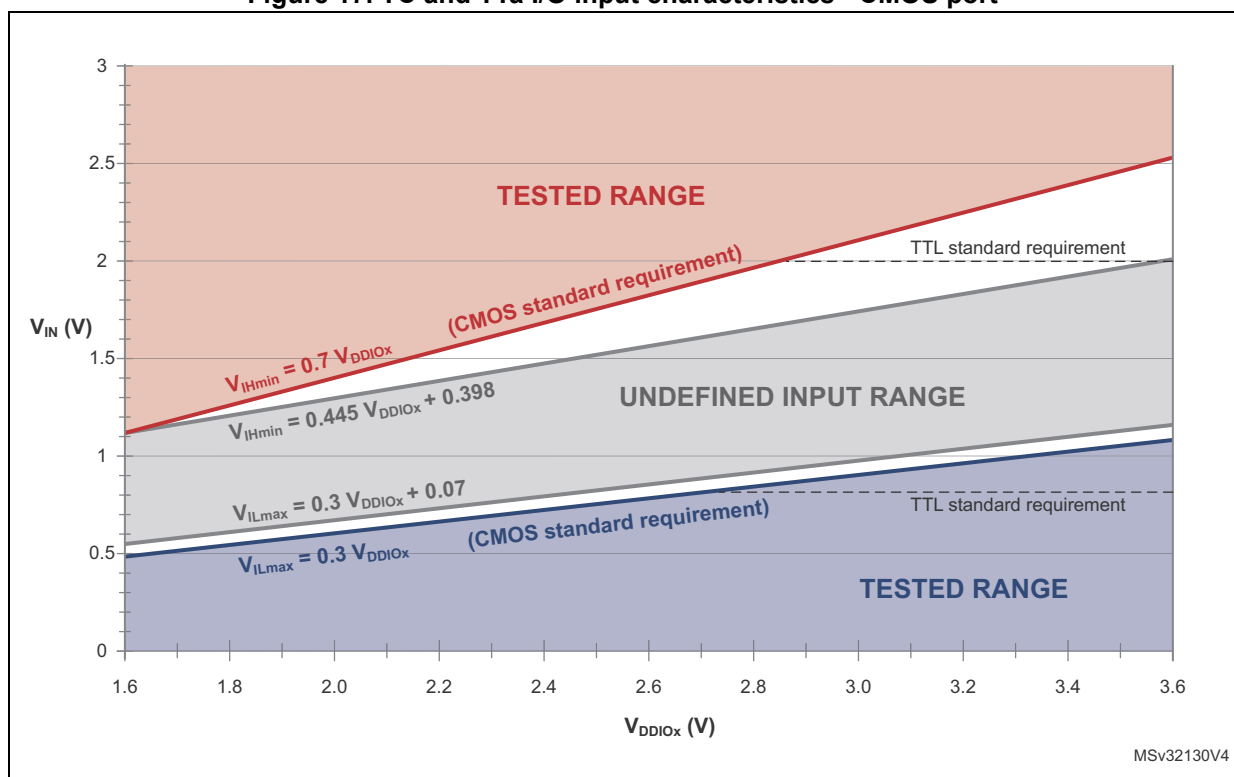
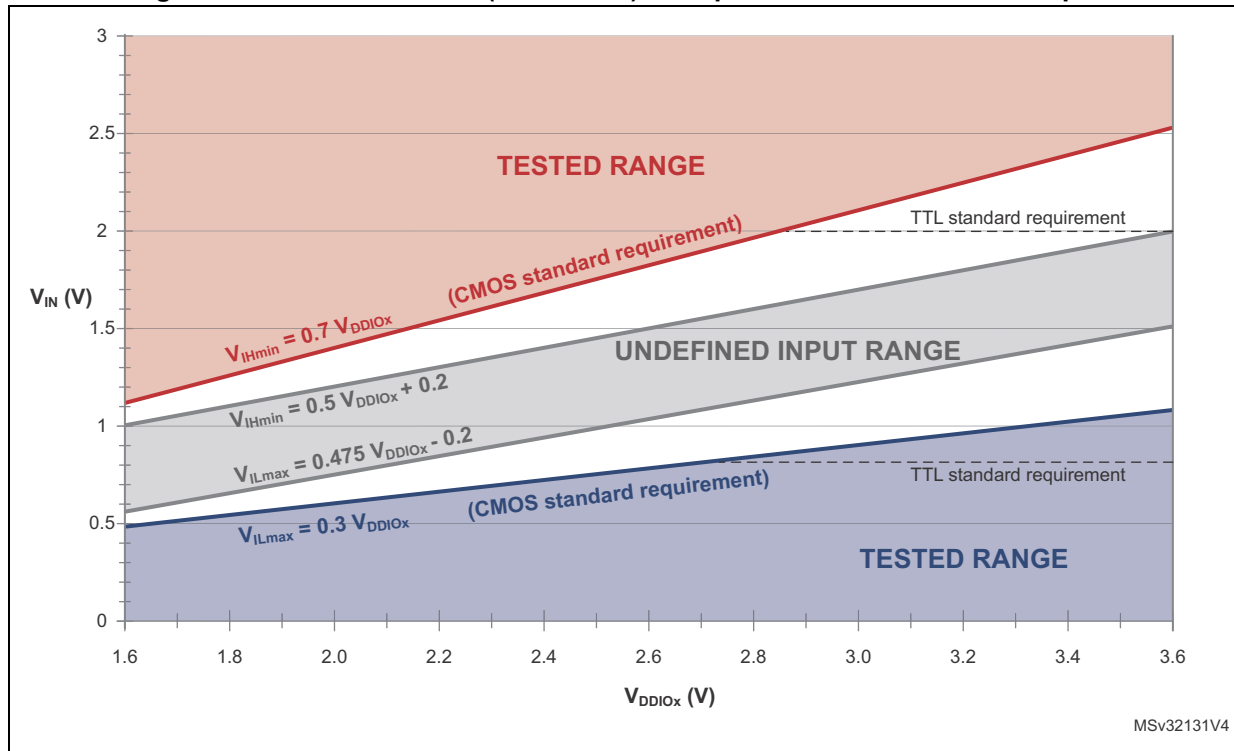


Figure 18. Five volt tolerant (FT and FTf) I/O input characteristics - CMOS port

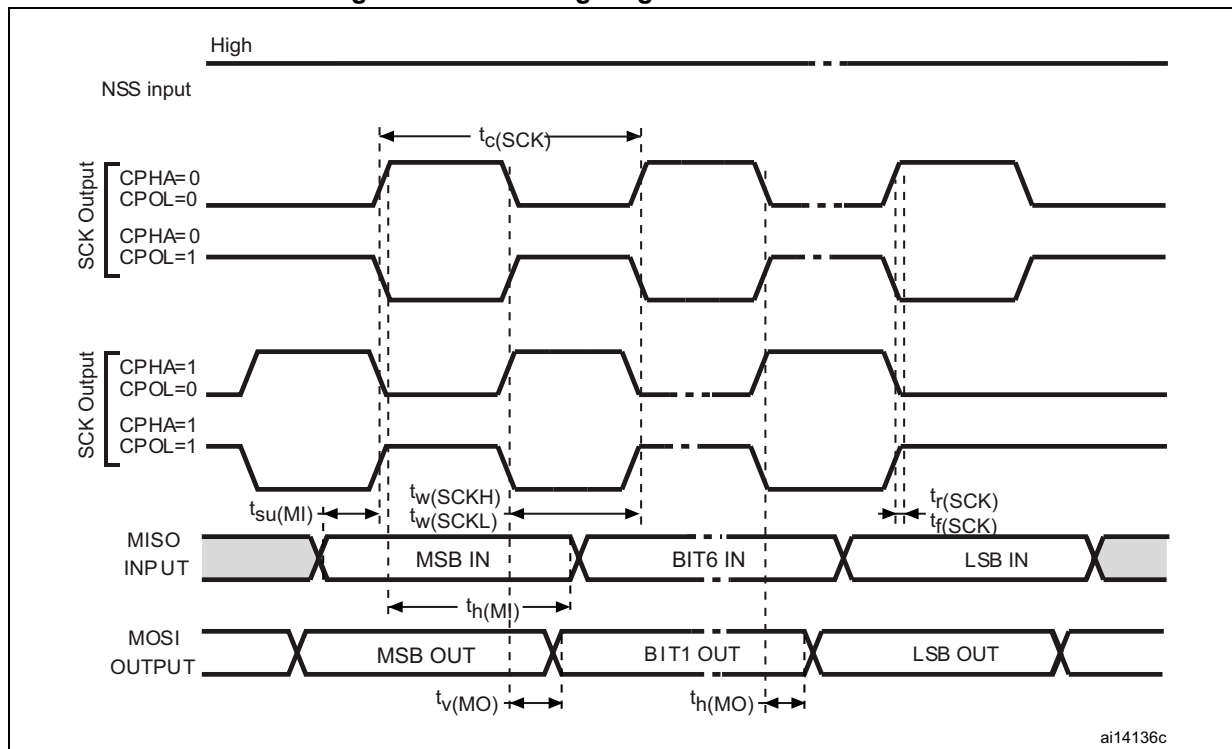


Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to ± 8 mA, and sink or source up to ± 20 mA (with a relaxed V_{OL}/V_{OH}).

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in [Section 6.2](#):

- The sum of the currents sourced by all the I/Os on all VDD_x and $VDDSDx$, plus the maximum Run consumption of the MCU sourced on V_{DD} cannot exceed the absolute maximum rating SI_{VDD} (see [Table 20](#)).
- The sum of the currents sunk by all the I/Os on all VSS_x and $VSSSD$, plus the maximum Run consumption of the MCU sunk on V_{SS} cannot exceed the absolute maximum rating SI_{VSS} (see [Table 20](#)).

Figure 24. SPI timing diagram - master mode⁽¹⁾

1. Measurement points are done at $0.5V_{DD}$ level and with external $C_L = 30 \text{ pF}$.

6.3.17 12-bit ADC characteristics

Unless otherwise specified, the parameters given in [Table 60](#) are preliminary values derived from tests performed under ambient temperature, f_{PCLK2} frequency and V_{DDA} supply voltage conditions summarized in [Table 22](#).

Note: *It is recommended to perform a calibration after each power-up.*

Table 60. ADC characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DDA}	Power supply	-	2.4	-	3.6	V
V_{REF+}	Positive reference voltage	-	2.4	-	V_{DDA}	V
V_{REF-}	Negative reference voltage	-	0	-	-	V
$I_{DDA(ADC)}^{(1)}$	Current consumption from V_{DDA}	$V_{DD} = V_{DDA} = 3.3$ V	-	0.9	-	mA
I_{VREF}	Current on the V_{REF} input pin	-	-	160 ⁽²⁾	220 ⁽²⁾	μA
f_{ADC}	ADC clock frequency	-	0.6	-	14	MHz
$f_S^{(3)}$	Sampling rate	-	0.05	-	1	MHz
$f_{TRIG}^{(3)}$	External trigger frequency	$f_{ADC} = 14$ MHz	-	-	823	kHz
		-	-	-	17	1/ f_{ADC}
V_{AIN}	Conversion voltage range	-	0 (V_{SSA} or V_{REF-} tied to ground)	-	V_{REF+}	V
$R_{SRC}^{(3)}$	Signal source impedance	See Equation 1 and Table 61 for details	-	-	50	kΩ
$R_{ADC}^{(3)}$	Sampling switch resistance	-	-	-	1	kΩ
$C_{ADC}^{(3)}$	Internal sample and hold capacitor	-	-	-	8	pF
$t_{CAL}^{(3)}$	Calibration time	$f_{ADC} = 14$ MHz	5.9			μs
		-	83			1/ f_{ADC}
$t_{lat}^{(3)}$	Injection trigger conversion latency	$f_{ADC} = 14$ MHz	-	-	0.214	μs
		-	-	-	2 ⁽⁴⁾	1/ f_{ADC}
$t_{latr}^{(3)}$	Regular trigger conversion latency	$f_{ADC} = 14$ MHz	-	-	0.143	μs
		-	-	-	2 ⁽⁴⁾	1/ f_{ADC}
$t_S^{(3)}$	Sampling time	$f_{ADC} = 14$ MHz	0.107	-	17.1	μs
		-	1.5	-	239.5	1/ f_{ADC}
$t_{STAB}^{(3)}$	Power-up time	-	-	-	1	μs
$t_{CONV}^{(3)}$	Total conversion time (including sampling time)	$f_{ADC} = 14$ MHz	1	-	18	μs
		-	14 to 252 (t_S for sampling + 12.5 for successive approximation)			1/ f_{ADC}

1. During conversion of the sampled value (12.5 x ADC clock period), an additional consumption of 100 μA on I_{DDA} and 60 μA on I_{DD} is present
2. Guaranteed by characterization results.
3. Guaranteed by design.
4. For external triggers, a delay of 1/ f_{PCLK2} must be added to the latency specified in [Table 60](#)

Table 74. SDADC characteristics (continued)⁽¹⁾

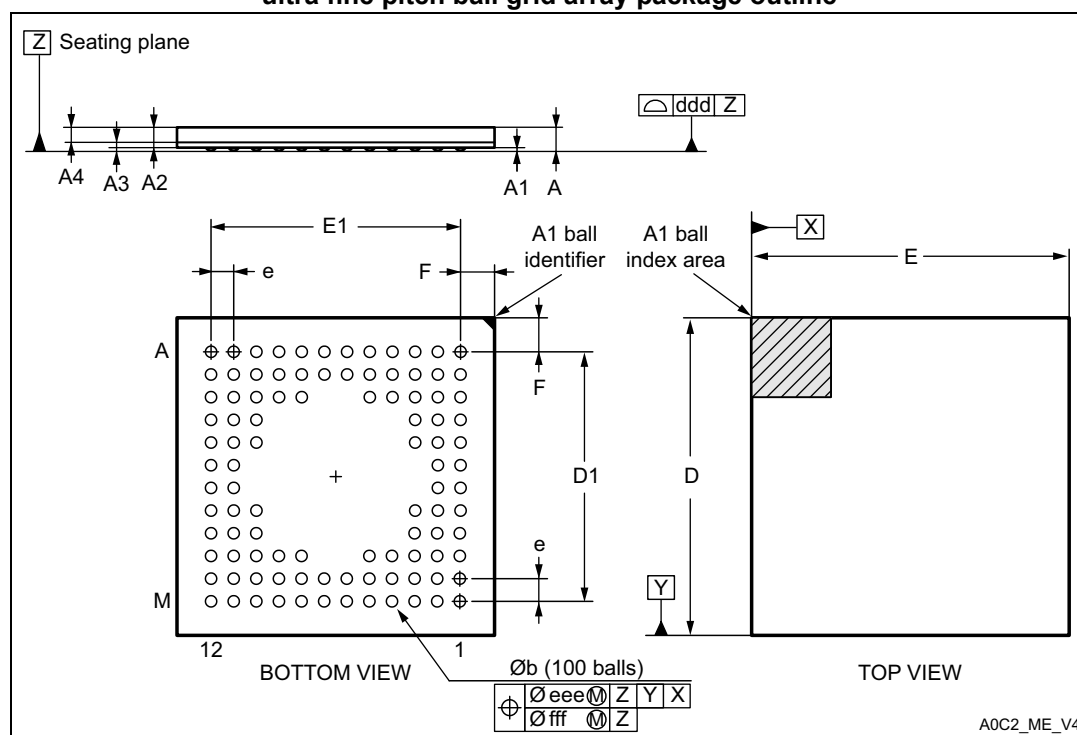
Symbol	Parameter	Conditions					Min	Typ	Max	Unit	Note
SNR ⁽⁵⁾	Signal to noise ratio	Differential mode	gain = 1	$f_{\text{ADC}} = 1.5 \text{ MHz}$	$V_{\text{DDSDx}} = 3.3$	$V_{\text{REFSD+}} = 3.3^{(3)}$	84	85	-	dB	-
				$f_{\text{ADC}} = 6 \text{ MHz}$		$V_{\text{REFSD+}} = 1.2^{(4)}$	86	88	-		
						$V_{\text{REFSD+}} = 3.3$	88	92	-		
			gain = 8	$f_{\text{ADC}} = 6 \text{ MHz}$		$V_{\text{REFSD+}} = 1.2^{(4)}$	76	78	-		
						$V_{\text{REFSD+}} = 3.3$	82	86	-		
				$f_{\text{ADC}} = 1.5 \text{ MHz}$		$V_{\text{REFSD+}} = 3.3^{(3)}$	76	80	-		
		Single ended mode	gain = 1	$f_{\text{ADC}} = 1.5 \text{ MHz}$		$V_{\text{REFSD+}} = 3.3$	80	84	-		
				$f_{\text{ADC}} = 6 \text{ MHz}$		$V_{\text{REFSD+}} = 1.2^{(4)}$	77	81	-		
						$V_{\text{REFSD+}} = 3.3$	85	90	-		
			gain = 8	$f_{\text{ADC}} = 6 \text{ MHz}$		$V_{\text{REFSD+}} = 1.2^{(4)}$	66	71	-		
						$V_{\text{REFSD+}} = 3.3$	74	78	-		

7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

7.1 UFBGA100 package information

Figure 32. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package outline



1. Drawing is not to scale.

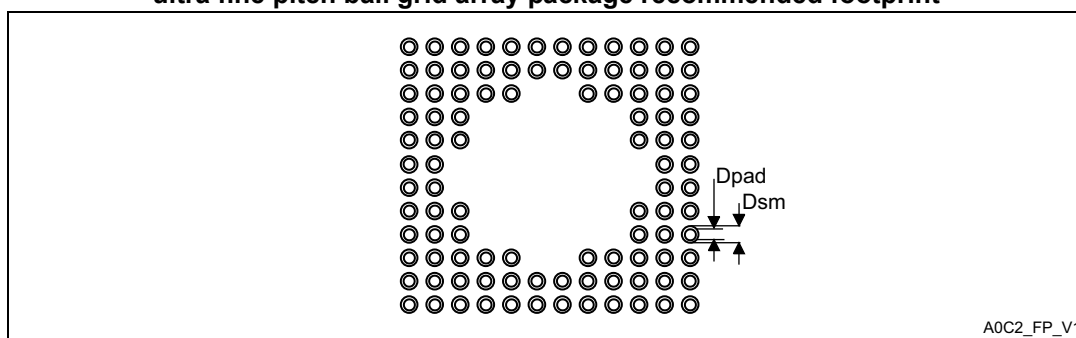
Table 76. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	0.460	0.530	0.600	0.0181	0.0209	0.0236
A1	0.050	0.080	0.110	0.0020	0.0031	0.0043
A2	0.400	0.450	0.500	0.0157	0.0177	0.0197
A3	-	0.130	-	-	0.0051	-
A4	0.270	0.320	0.370	0.0106	0.0126	0.0146
b	0.200	0.250	0.300	0.0079	0.0098	0.0118

Table 76. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data (continued)

Symbol	millimeters			inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D	6.950	7.000	7.050	0.2736	0.2756	0.2776
D1	5.450	5.500	5.550	0.2146	0.2165	0.2185
E	6.950	7.000	7.050	0.2736	0.2756	0.2776
E1	5.450	5.500	5.550	0.2146	0.2165	0.2185
e	-	0.500	-	-	0.0197	-
F	0.700	0.750	0.800	0.0276	0.0295	0.0315
ddd	-	-	0.100	-	-	0.0039
eee	-	-	0.150	-	-	0.0059
fff	-	-	0.050	-	-	0.0020

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 33. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package recommended footprint**Table 77. UFBGA100 recommended PCB design rules (0.5 mm pitch BGA)**

Dimension	Recommended values
Pitch	0.5
Dpad	0.280 mm
Dsm	0.370 mm typ. (depends on the soldermask registration tolerance)
Stencil opening	0.280 mm
Stencil thickness	Between 0.100 mm and 0.125 mm

Table 78. LQPF100 - 100-pin, 14 x 14 mm low-profile quad flat package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	15.800	16.000	16.200	0.6220	0.6299	0.6378
D1	13.800	14.000	14.200	0.5433	0.5512	0.5591
D3	-	12.000	-	-	0.4724	-
E	15.800	16.000	16.200	0.6220	0.6299	0.6378
E1	13.800	14.000	14.200	0.5433	0.5512	0.5591
E3	-	12.000	-	-	0.4724	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0.0°	3.5°	7.0°	0.0°	3.5°	7.0°
ccc	-	-	0.080	-	-	0.0031

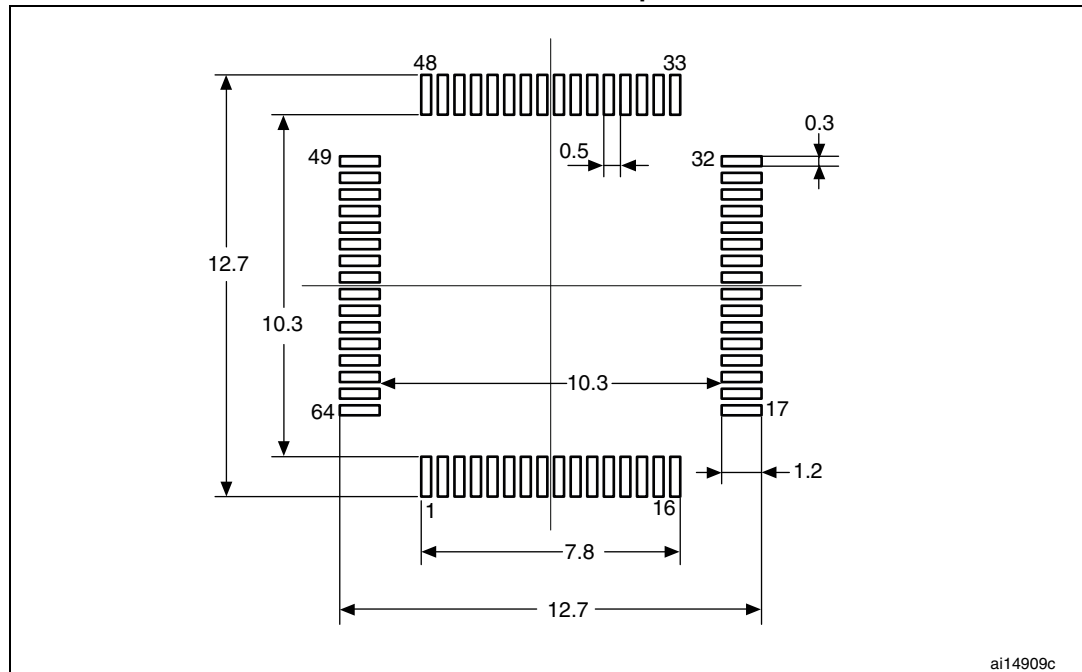
1. Values in inches are converted from mm and rounded to 4 decimal digits.

Table 79. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	-	12.000	-	-	0.4724	-
D1	-	10.000	-	-	0.3937	-
D3	-	7.500	-	-	0.2953	-
E	-	12.000	-	-	0.4724	-
E1	-	10.000	-	-	0.3937	-
E3	-	7.500	-	-	0.2953	-
e	-	0.500	-	-	0.0197	-
K	0°	3.5°	7°	0°	3.5°	7°
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 39. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package recommended footprint

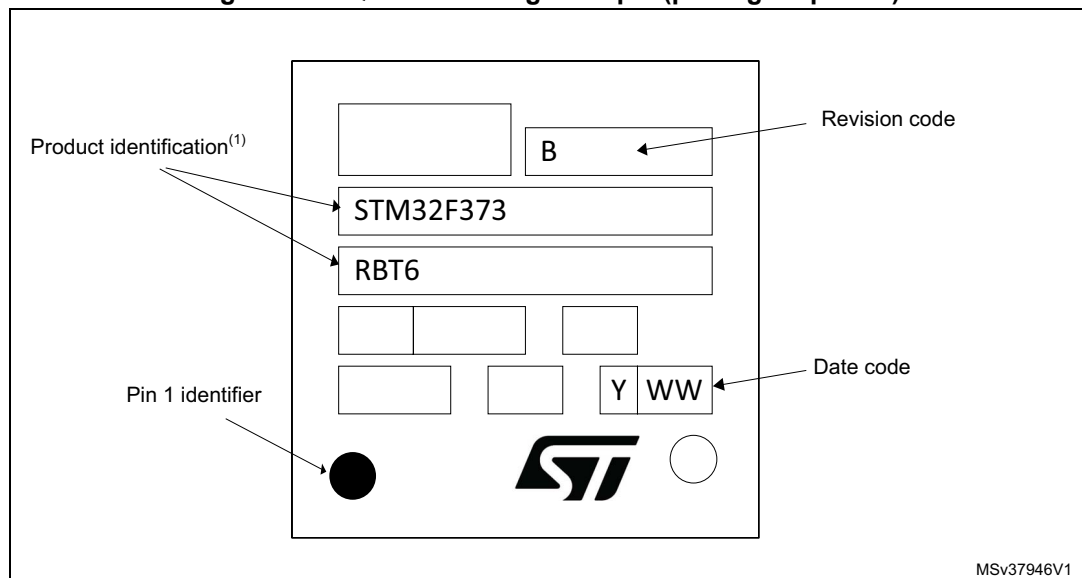


1. Dimensions are expressed in millimeters.

Device marking for LQFP64

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

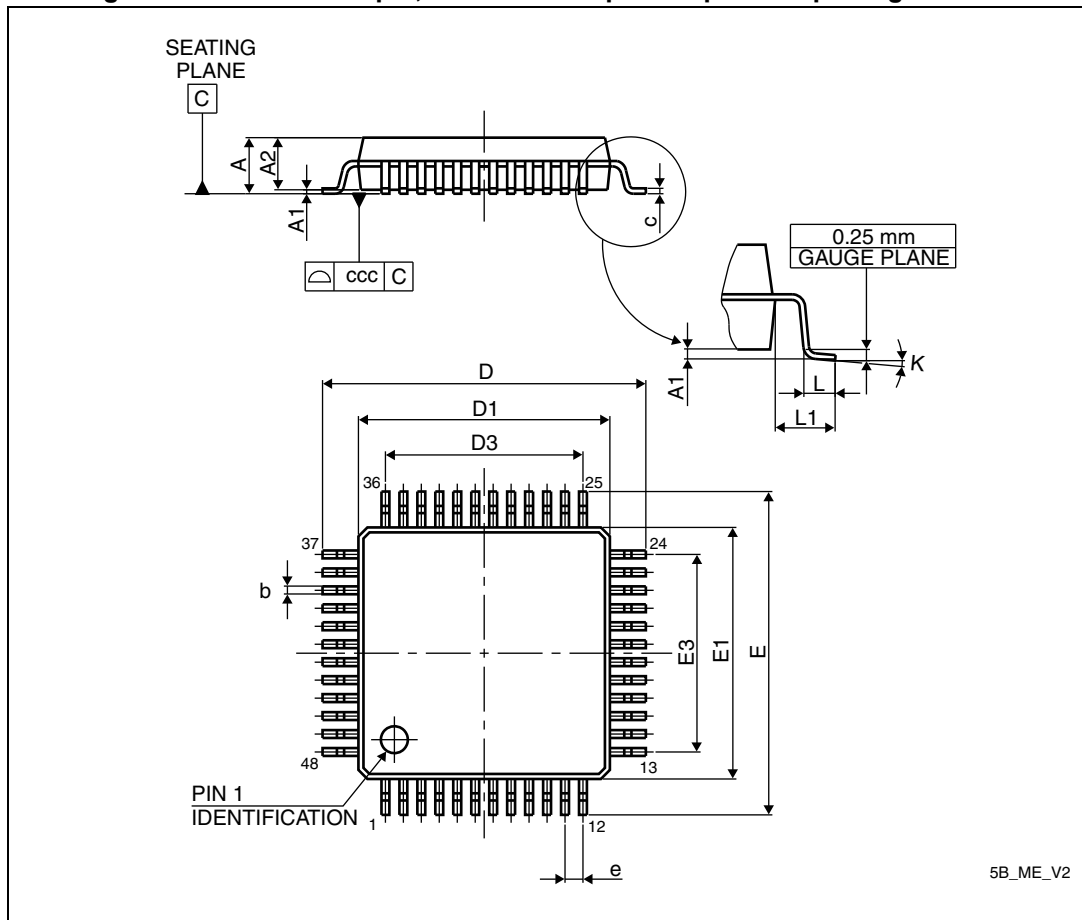
Figure 40. LQFP64 marking example (package top view)



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering samples to run qualification activity.

7.4 LQFP48 package information

Figure 41. LQFP48 - 48-pin, 7 x 7 mm low-profile quad flat package outline



1. Drawing is not to scale.